

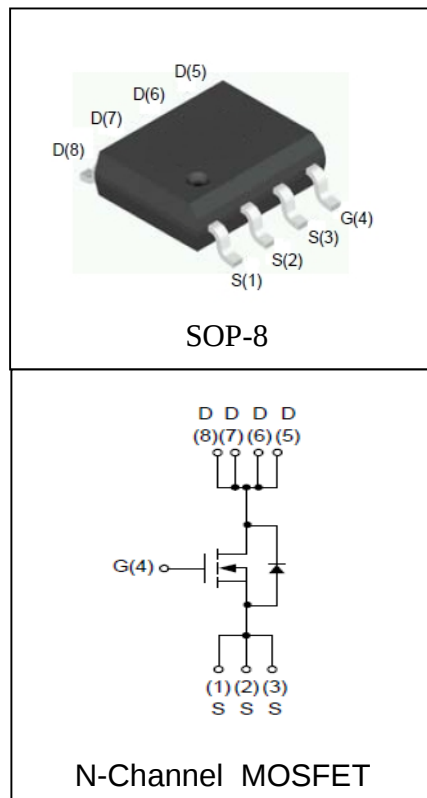
Features

- 25V/13A,
 $R_{DS(ON)} = 9m\Omega$ (Typ.) @ $V_{GS}=10V$
 $R_{DS(ON)} = 14.5m\Omega$ (Typ.) @ $V_{GS}=4.5V$
- Super High Dense Cell Design
- Fast Switching and Fully Avalanche Rated
- 100% avalanche tested
- Lead Free and Green Available

Applications

- Power Management in Notebook Computer, and DC-DC Converters in Networking Systems.

Pin Description



Absolute Maximum Ratings

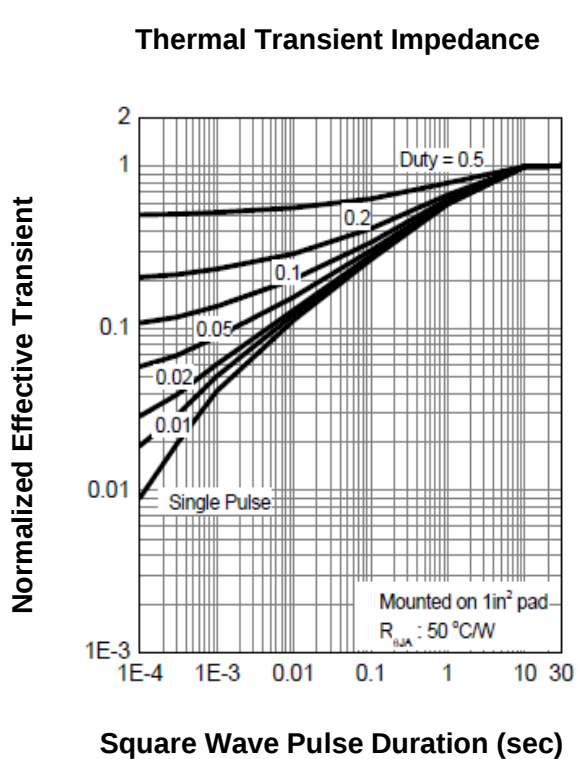
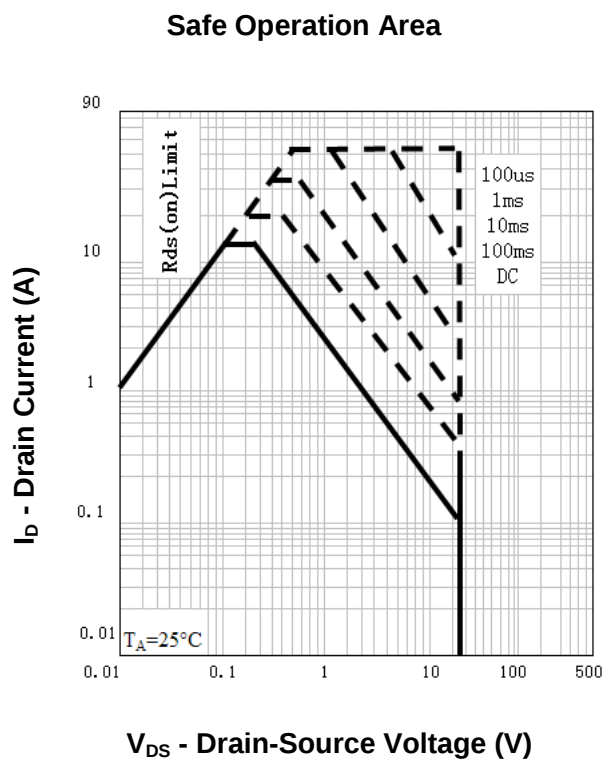
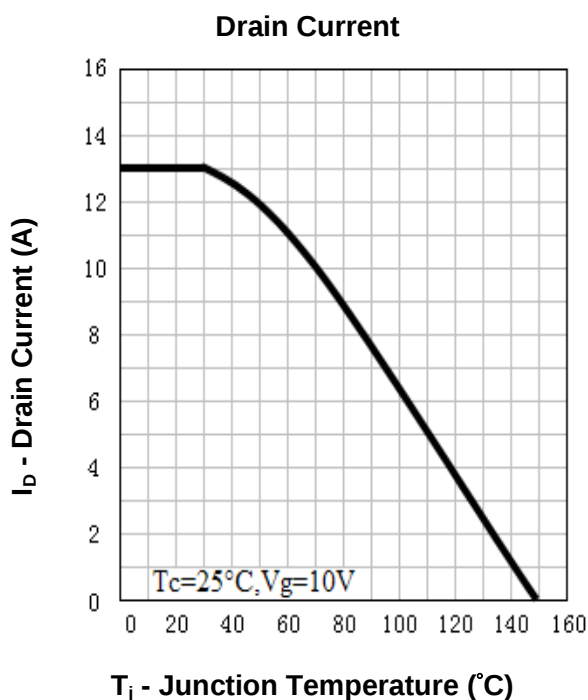
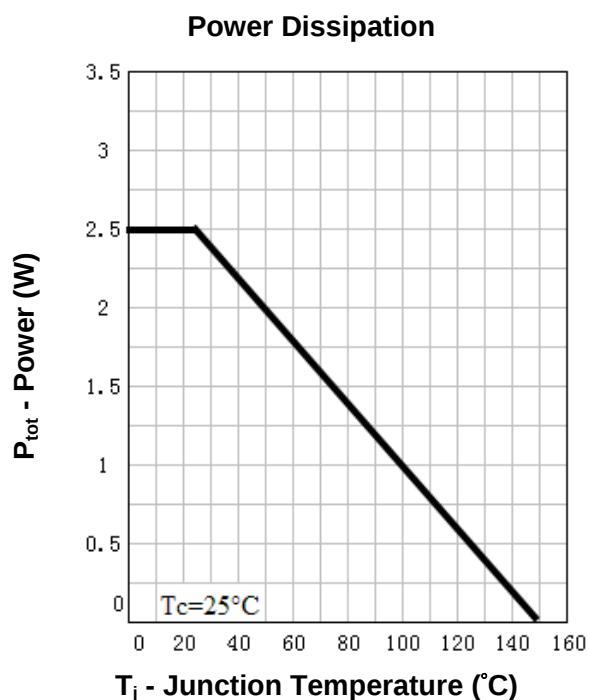
Symbol	Parameter		Rating	Unit
Common Ratings (T _A =25°C Unless Otherwise Noted)				
V _{DSS}	Drain-Source Voltage		25	V
V _{GSS}	Gate-Source Voltage		±20	
T _J	Maximum Junction Temperature		150	°C
T _{STG}	Storage Temperature Range		-55 to 150	°C
I _S	Diode Continuous Forward Current	T _C =25°C	13	A
Mounted on Large Heat Sink				
I _{DP}	300μs Pulse Drain Current Tested	T _C =25°C	52 ^①	A
I _D	Continuous Drain Current(V _{GS} =10V)	T _C =25°C	13	A
		T _C =70°C	9.8	
P _D	Maximum Power Dissipation	T _C =25°C	2.5	W
		T _C =70°C	1.6	
R _{θJA} ^②	Thermal Resistance-Junction to Ambient		50	°C/W
Drain-Source Avalanche Ratings				
E _{AS} ^③	Avalanche Energy, Single Pulsed		110	mJ

Electrical Characteristics ($T_A=25^{\circ}\text{C}$ Unless Otherwise Noted)

Symbol	Parameter	Test Condition	RU2520H			Unit
			Min.	Typ.	Max.	
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _{DS} =250μA	25			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 25V, V _{GS} =0V			1	μA
		T _J =85°C			30	
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =250μA	1.5	2	2.7	V
I _{GSS}	Gate Leakage Current	V _{GS} =±20V, V _{DS} =0V			±100	nA
R _{DS(ON)} ④	Drain-Source On-state Resistance	V _{GS} = 10V, I _{DS} =10A		9	11	mΩ
		V _{GS} = 4.5V, I _{DS} =8A		14.5	16	mΩ
Diode Characteristics						
V _{SD} ④	Diode Forward Voltage	I _{SD} =13A, V _{GS} =0V			1.2	V
t _{rr}	Reverse Recovery Time	I _{SD} =13A, dI _{SD} /dt=100A/μs		89		ns
Q _{rr}	Reverse Recovery Charge			175		nC
Dynamic Characteristics ⑤						
R _G	Gate Resistance	V _{GS} =0V, V _{DS} =0V, F=1MHz		1.2		Ω
C _{iss}	Input Capacitance	V _{GS} =0V, V _{DS} = 15V, Frequency=1.0MHz		980		pF
C _{oss}	Output Capacitance			160		
C _{rss}	Reverse Transfer Capacitance			120		
t _{d(ON)}	Turn-on Delay Time	V _{DD} =15V, R _L =30Ω, I _{DS} =13A, V _{GEN} = 10V, R _G =6Ω		12		ns
t _r	Turn-on Rise Time			18		
t _{d(OFF)}	Turn-off Delay Time			35		
t _f	Turn-off Fall Time			16		
Gate Charge Characteristics ⑤						
Q _g	Total Gate Charge	V _{DS} =15V, V _{GS} = 10V, I _{DS} =13A		19	25	nC
Q _{gs}	Gate-Source Charge			3		
Q _{gd}	Gate-Drain Charge			7		

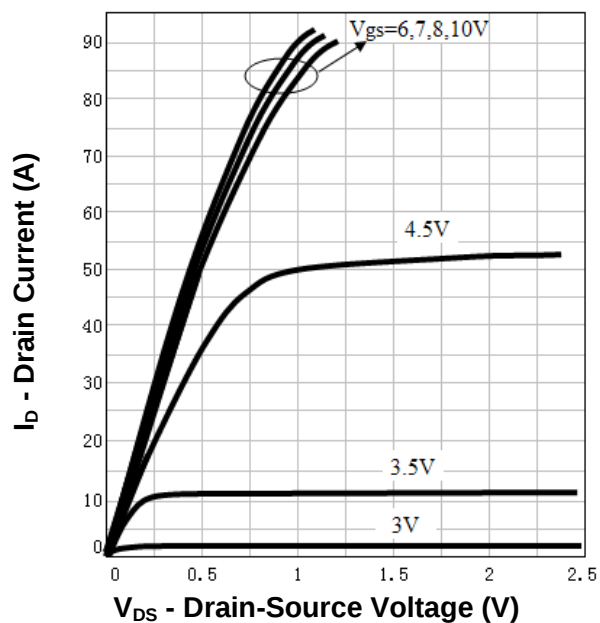
- Notes: ① Pulse width limited by safe operating area.
 ② When mounted on 1 inch square copper board, $t \leq 10\text{sec}$.
 ③ Limited by T_{Jmax} , $I_{AS}=21A$, $V_{DD}=48V$, $R_G=50\Omega$, Starting $T_J=25^{\circ}\text{C}$.
 ④ Pulse test ; Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
 ⑤ Guaranteed by design, not subject to production testing.

Typical Characteristics

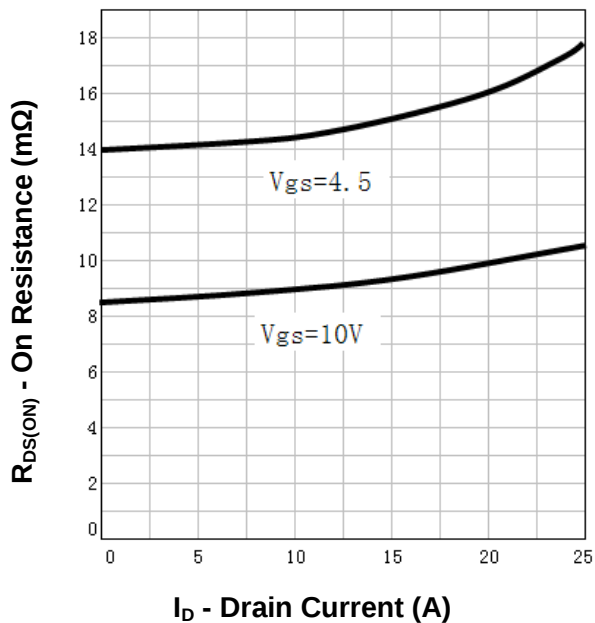


Typical Characteristics

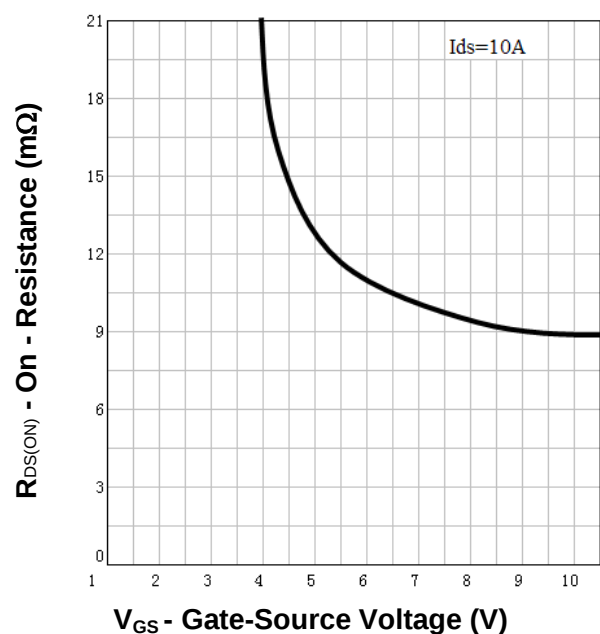
Output Characteristics



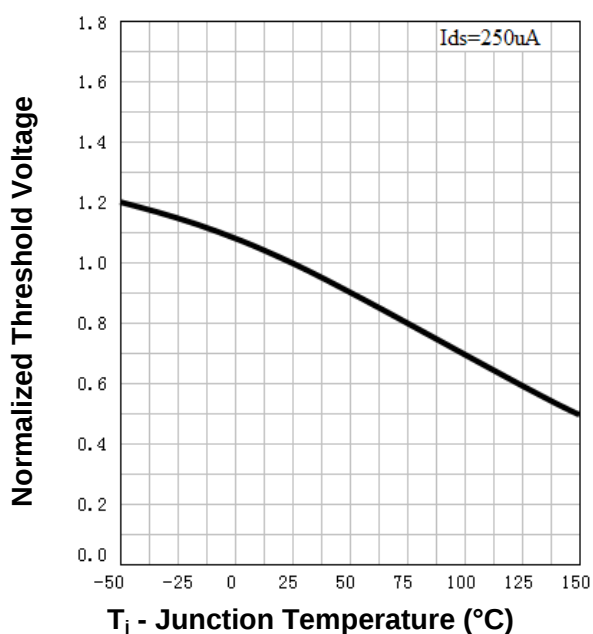
Drain-Source On Resistance



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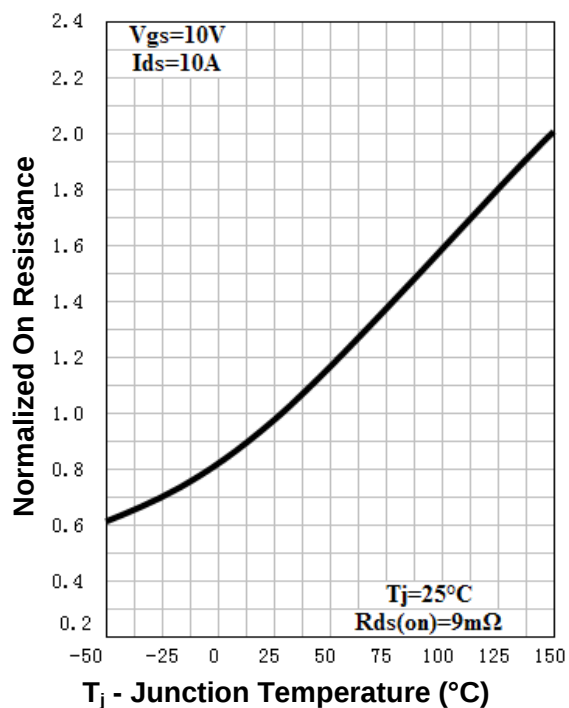


Gate Threshold Voltage

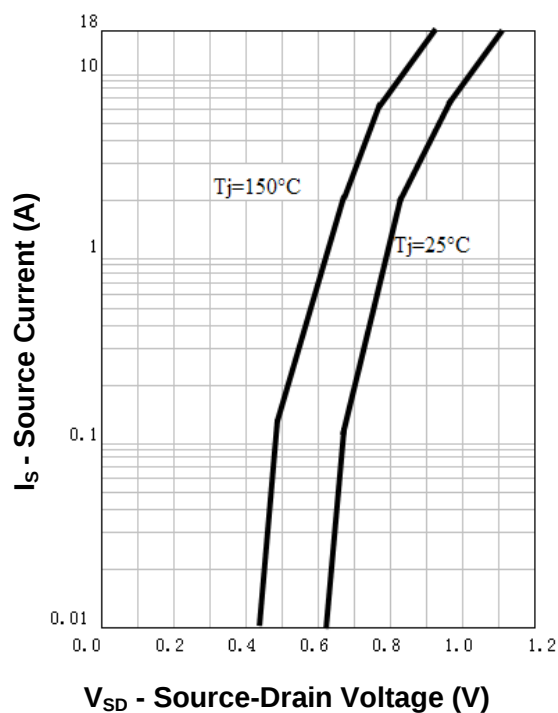


Typical Characteristics

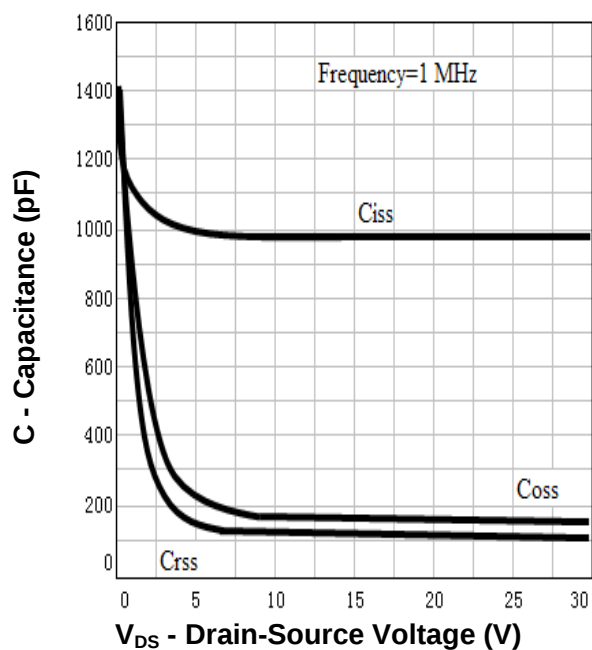
Drain-Source On Resistance



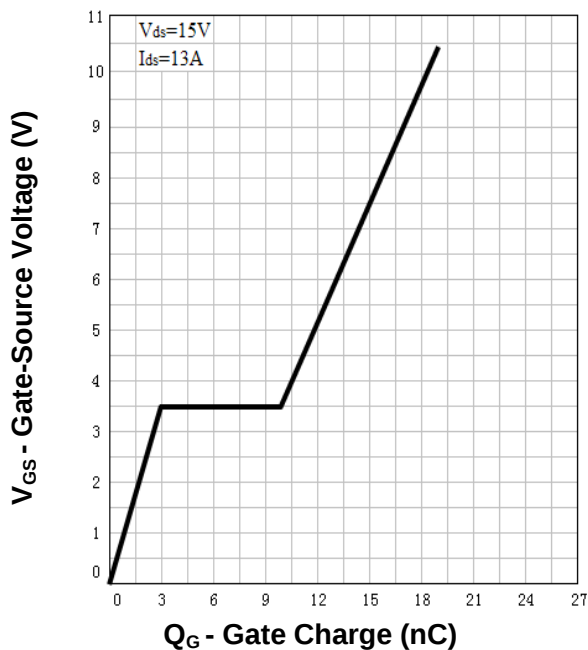
Source-Drain Diode Forward



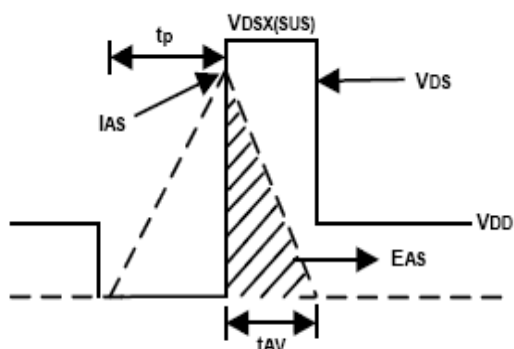
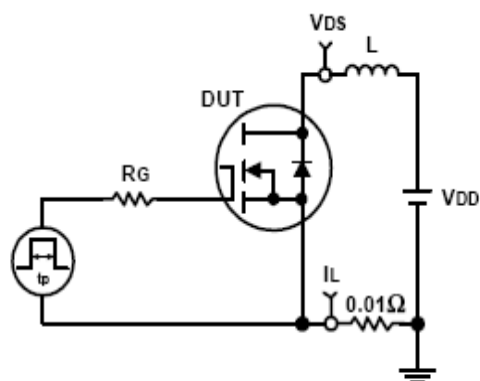
Capacitance



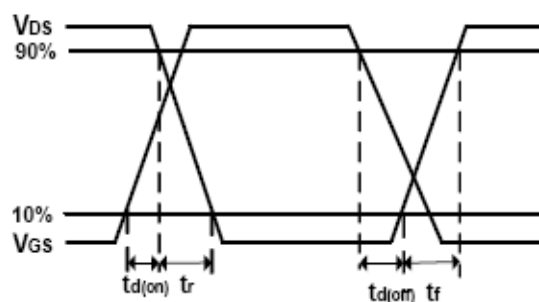
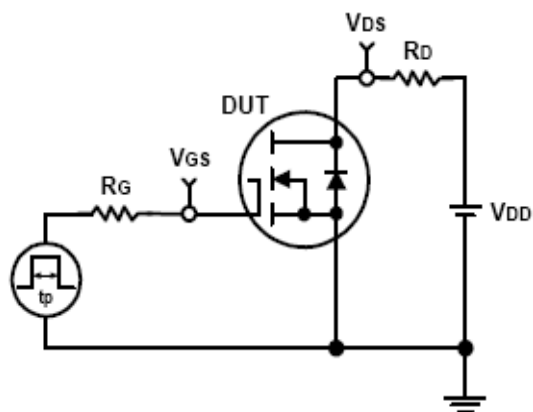
Gate Charge



Avalanche Test Circuit and Waveforms



Switching Time Test Circuit and Waveforms

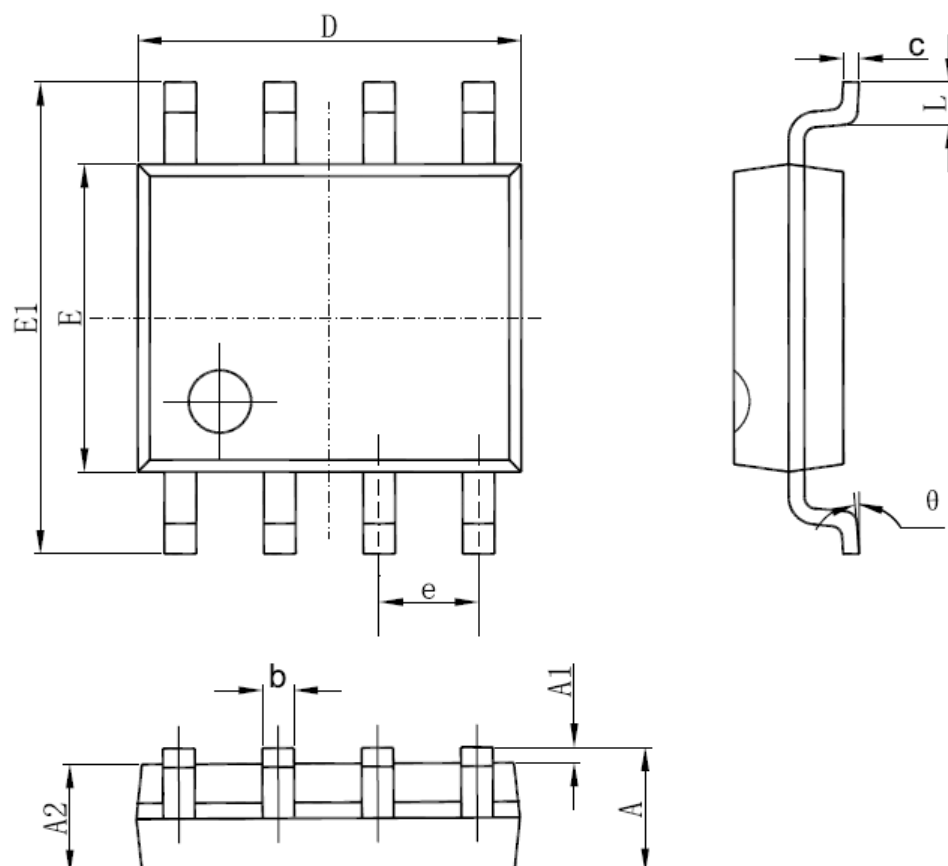


Ordering and Marking Information

Device	Marking	Package	Packaging	Quantity	Reel Size	Tape width
RU2520H	RU2520H	SOP-8	Tape&Reel	2500	13''	12mm

Package Information

SOP-8



SYMBOL	MM		INCH		SYMBOL	MM		INCH	
	MIN	MAX	MIN	MAX		MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069	E	3.800	4.000	0.150	0.157
A1	0.100	0.250	0.004	0.010	E1	5.800	6.200	0.228	0.244
A2	1.350	1.550	0.053	0.061	e	1.270 (BSC)		0.050 (BSC)	
b	0.330	0.510	0.013	0.020	L	0.400	1.270	0.016	0.050
c	0.170	0.250	0.006	0.010	θ	0°	8°	0°	8°
D	4.700	5.100	0.185	0.200					

ALL DIMENSIONS REFER TO JEDEC STANDARD
DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS

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